Im aginary chem ical potential quantum M onte C arlo for H ubbard m olecules

Fei Lin, Jurij Smakov, Erik S.S rensen, Catherine Kallin and A.John Berlinsky Department of Physics and Astronomy, M cM aster University, Hamilton, Ontario, Canada L8S 4M 1 (Dated: March 22, 2024)

W e generalize the imaginary chemical potential quantum M onte C arb (QMC) m ethod proposed by D agotto et al. [Phys. Rev. B 41, R811 (1990)] to system s without particle-hole symmetry. The generalized m ethod is tested by comparing the results of the QMC simulations and exact diagonalization on sm all H ubbard m olecules, such as tetrahedron and truncated tetrahedron. Results of the application of the m ethod to the C $_{60}$ H ubbard m olecule are discussed.

PACS num bers: 71.10 Li, 02.70.Ss, 74.70 W z

I. IN TRODUCTION

K now ledge of the evolution of energy levels with doping in strongly correlated system s is of signi cant in portance for understanding the physical mechanism s leading to their unconventional properties. For example, inform ation about the changes in the ground state energy of m odel electron system s (such as Hubbard model) upon electron or hole doping may be used to con m or disprove hypotheses about the origin of the pairing mechanism, eventually leading to superconductivity. A s accessing this inform ation analytically usually requires the use of various approxim ations, num erical techniques are often the only tools which can provide unbiased estim ates for the observables of interest.

We have recently applied the auxiliary eld quantum M onte Carlo (AFQMC) on a C_{60} molecule to extract the electronic binding energies [1]. AFQMC has been widely used in Hubbard H am iltonian simulations since its introduction by B lankenbecler et al. [2, 3], and its further development by H irsch [4] and W hite et al. [5]. Being a nite-tem perature technique, AFQMC does not allow easy access to the physical observables, not represented by therm odynam ic averages, such as energy gaps. A convenient procedure to extract this additional inform ation from the AFQMC data was proposed by D agotto et al. [6], who introduced im aginary chem ical potentials in AFQMC simulations. It was then used to extract the charge gaps of the one-band Hubbard m odel on nite two-dim ensional (2D) square lattices.

In the present paper we generalize this form alism to system s without particle-hole symmetry, such as the tetrahedron, truncated tetrahedron and C₆₀ molecules. The canonical partition function ratios are obtained from the expansions of the AFQMC determ inant ratios for a set of nite temperatures T, which are subsequently used to extract charge gaps at low temperatures. This generalization results in the appearance of an extra phase factor in the expansion of the determ inant ratios, which reduces to unity in the particle-hole symmetric system s.

The rest of the paper is organized as follows. First, we brie y describe the imaginary chemical potential QMC (ICPQMC) formalism. Then simulation results on some Hubbard molecules are presented to illustrate ourm ethod. The results are compared with the data obtained by exact diagonalization (ED) on smallm olecules and projectorQMC (PQMC) on larger ones.

II. M ETHODOLOGY

W e start with an expansion of the grand canonical partition function $Z_{GC}()$ in terms of canonical partition functions $Z_C(n)$ [6]:

$$Z_{GC}() = Tre \quad \stackrel{(\hat{H} \quad \hat{N})}{=} e^{N} \quad e^{n} Z_{C}(n); \quad (1)$$

where = $1 = (k_B T)$ is the inverse temperature, is the chemical potential, n is the deviation of the particle num – ber from half-lling (positive or negative, denoting electron or hole doping, respectively) in canonical ensemble, \hat{N} is the electron number operator, and N is the num – ber of spatial lattice sites in the system. \hat{H} is the usual one-band H ubbard H am iltonian:

$$H = \begin{array}{c} X \\ H_{ij} (c_i^{v} c_j + h c;) + U \\ & n_{i''} n_{i\#} \\ & i \end{array} \begin{array}{c} U \\ Z \\ i \\ & i \end{array} \begin{array}{c} X \\ n_{i} : \\ & i \end{array}$$

The sum mation in the hopping term t_{ij} is performed over all nearest-neighbor pairs of the Hubbard molecule. For the C₆₀ molecule we have set $t_{ij} = t$ for the links between the pentagons and hexagons and $t_{ij} = 1.2t$ for the links between hexagons. In all other cases t_{ij} was set equal to t for all links, with t used as an energy unit. U is the on-site C oulomb repulsion (Hubbard) term, and an extra diagonal term has been added to the H am iltonian so that

= 0 corresponds to half-lling on bipartite lattices.

Following D agotto et al. [6], we analytically continue Eq. (1) to imaginary chemical potential ! i, where is real. Then the inverse Fourier transform of Eq. (1) gives

$$Z_{C}(n) = \frac{Z_{2}}{2} d e^{i(n+N)} Z_{GC}(=i): \quad (3)$$

In AFQMC the grand canonical partition function is

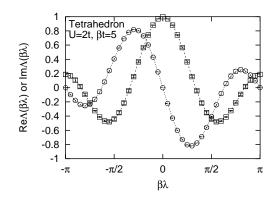


FIG.1: Fit of real (squares) and imaginary (circles) parts of determ inant ratios according to Eq. (12) for a tetrahedron m olecule.

given by

$$Z_{GC}() = \begin{bmatrix} X & Y \\ det[1 + B_{L}()B_{L-1}() & _{1}(B] \\ f_{X} & = 1 \end{bmatrix}$$

$$= \det 0 (f g;) * \det 0 (f g;) *;$$
(4)

where the ferm ion degrees of freedom have been traced out, and the B $_1$ m atrices are de ned as

$$B_1() = e^{K} e^{V} (1);$$
 (5)

$$(K)_{ij} = \begin{cases} t_{ij} & \text{for } i, j \text{ nearest neighbors;} \\ 0 & \text{otherw ise;} \end{cases}$$
(6)

$$V_{ij}(l) = _{ij}[_{i}(l) +]:$$
 (7)

Here is the imaginary time discretization intervaland $tanh^2$ (=2) = tanh (U=4). Thus, the original problem of taking a trace over ferm ionic degrees of freedom has been replaced by a problem of tracing over auxiliary Ising variables i (1), introduced at every space-time point (i;1). Inserting Eq. (4) into Eq. (3), we get

$$Z_{c}(n) = \begin{cases} X & Z_{2} = \\ \frac{1}{f g^{2}} & d e^{-i (n+N)} detO(f g; i) \\ detO(f g; i)_{\#} : \end{cases}$$
(8)

D ividing Eq. (8) by Z_{GC} (= 0) from Eq. (4) yields

$$\frac{Z_{\rm C}(n)}{Z_{\rm GC}(0)} = \frac{X_{\rm f}}{f_{\rm g}} P(fg;0) \frac{Z_{\rm 2}}{2} de^{i n} () (9)$$

where

()
$$e^{i_N} \frac{\det 0 (f g; i) \cdot \det 0 (f g; i)_{\#}}{\det 0 (f g; 0) \cdot \det 0 (f g; 0)_{\#}};$$
 (10)

and

$$P (f g; 0) = \frac{\det 0 (f g; 0) \cdot \det 0 (f g; 0)_{\#}}{\int_{f g} \det 0 (f g; 0) \cdot \det 0 (f g; 0)_{\#}}$$
(11)

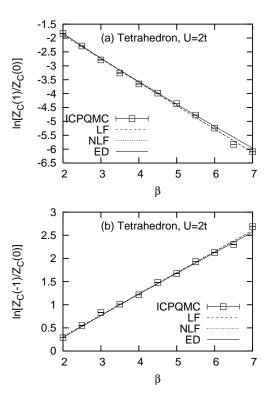


FIG.2: Fits of ICPQMC data for a tetrahedron molecule at low temperatures for electron (a) and hole (b) doping. NLF form s for (a) and (b) are given by Eq. (14) and Eq. (15). ED results are also shown for comparison.

is the probability distribution for Z_{GC} (0). Since there is always an energy gap above and below half-lling for any nite system, we expect the ferm ion determ inants to be nearly -independent at low tem peratures. Therefore, we can generate the Ising eld con gurations f g for = 0 and use these con gurations to calculate system properties at $\frac{6}{2}$ 0.

Similar to the expansion in Eq. (1), we expect that the determ inant ratio () in Eq. (10) can be expressed as $\cos p \, \text{lex Fourier series in the particle num ber n}$

$$() = c_{0}(fg) + \frac{X^{N}}{[c_{n}(fg) + c_{n}(fg)]cos(n)}$$

$$() = \frac{X^{N}}{(c_{n}(fg) + c_{n}(fg)]cos(n)}$$

$$(12)$$

$$(12)$$

where n (n) represents a doping of n electrons (holes) with respect to half-lling. Eq. (12) is real for system s with particle-hole symmetry, since then c_n (f g) = c_n (f g). When we substitute Eq. (12) back into Eq. (9), we see that Z_c (n)= Z_{GC} (0) = $hc_n i$, where the average h:::i is over the Ising eld con gurations f g generated from the probability distribution P (f g;0). In the case of negative weight we replace P by its absolute value P j and include a sign S = P = P j in the average: Z_c (n)= Z_{GC} (0) = $hc_n S i=hS i$. The average h:::i

		LF	NLF	ED (PQMC)
C 4	1;0	0.85(1)	0.87(2)	0.82843
(U = 2t)	1;0	-0.458 (9)	-0.358 (9)	-0.34949
	2;1	1.9(1)	2.0(1)	2.0
	2; 1	-0.400 (6)	-0.397 (6)	-0.40466
C 8	1;0	1,20(2)	1,27(2)	1,26224
(U = 4t)	2; 1	1.44 (3)	1.5(2)	1,27490
C 12	1;0	0.81(1)	0.997 (7)	0.99596
(U = 2t)	1;0	0.041(1)	0.10(1)	0.07408
C 60	1;0	0.43 (5)	0.57(3)	0:561(7)
(U = 4t)	1;0	0.9(1)	0.88(4)	0:86(2)

TABLE I: ICPQMC results on tetrahedron (C₄), cube (C₈), truncated tetrahedron (C₁₂) and C₆₀ molecules. $_{n;0} =$ E (n) E (0) is the energy di erence between the ground states of the two llings. D ata marked by are PQMC results, as described in Section IIIB.

now refers to the probability distribution \mathcal{P} j. As we are interested in regions near half-lling, the sign problem does not lim it the applicability of our method.

At low temperatures the canonical partition function ratio will be dominated by $_{n;0} = E(n) = E(0)$, the energy dimension between the ground states for the two llings, and will take the form [6]

$$\frac{Z_{c}(n)}{Z_{c}(0)} = \frac{hc_{n}i}{hc_{0}i} ! d_{n;0}e^{n;0} \text{ as } ! 1; \quad (13)$$

where $d_{n,0} = d_n = d_0$, with d_n being the degeneracy of the ground state at lling n. When there is an energy level close to the ground state (produced by the elementary excitations such as spin waves), we include it explicitly in the tting expressions:

$$\frac{Z_{\rm C}(n)}{Z_{\rm C}(0)} = \frac{h_{\rm Cn}i}{h_{\rm C0}i} \cdot \frac{d_{\rm n,j0}e^{-\frac{n+0}{s_{\rm W}}} + f_{\rm n,j0}e^{-\frac{n}{s_{\rm W}}}}{1 + f_{\rm 0,j0}e^{-\frac{0}{s_{\rm W}}}}$$

$$as \quad \frac{1}{\frac{1}{n,j0};\frac{1}{s_{\rm W}}} \cdot$$
(14)

Here $f_{n,0} = d_{SW}^n = d_0$, where d_{SW}^n is the degeneracy of the spin wave state at lling n, and $_{SW}^n = E_{SW}$ (n) E (0) are the spin-wave gaps at lling n with respect to the ground state at half-lling.

Based on the above discussion, we form ulate the following calculation procedure:

- 1. Generate the Ising eld con guration f g according to the probability distribution P (f g;0) in the AFQMC simulation of Z_{GC} (0).
- 2. Evaluate the average of the determ inant ratio on the left-hand side of Eq. (12) over the Ising eld con gurations for a set of values.
- 3. Fit the real and in aginary parts of Eq. (12) respectively to determ ine the average values of $hc_n i$, n = 0; 1; 2;:::. From now on we will refer to these values simply as c_n .

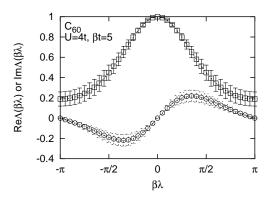


FIG.3: Fits of the real (squares) and in aginary (circles) parts of determ inant ratios according to Eq. (12) for a C $_{60}$ m olecule.

4. Fit the canonical partition function ratios $Z_{c}(n)=Z_{c}(0) = c_{n}=c_{0}, n = 1; 2; ::: with low temperature canonical partition function ratio expressions (13) or (14) to obtain energy gaps. Below we will refer to these ts as linear (LF) and non-linear (NLF), respectively.$

III. A P P L IC A T IO N

ICPQMC simulations have been carried out on tetrahedron, cube, truncated tetrahedron and C $_{60}$ m olecules. For each molecule, we have run the simulations at tem peratures t = 2:0;2:5;;6:5;7:0. The imaginary chem ical potential i was chosen so that 0 < < = , and we used a set of 20 evenly distributed values in this range. We have num erically checked that the real part of Eq. (12) is an even function around = 0, while the imaginary part is odd. Using this property, we have m apped out the determ inant ratio data for > 0. For the special particle-hole symmetric case, such as a 2D square lattice, we have tested our program s for the 2 2 and 4 4 systems, reproducing the results of Ref. [6].

A. Tetrahedron, Cube and Truncated Tetrahedron

Fig. 1 displays the t of the real and in aginary parts of Eq. (12) for a tetrahedron m olecule (C_4). Sim ilar ts were performed for data at all temperatures, generating a set of coe cients c_n . K now ledge of these coe cients enables us to calculate the partition function ratios at various temperatures, and, at low temperatures, to linearly t the logarithm of these ratios to obtain the energy gaps and degeneracy ratios. R esults of this procedure are presented in Fig. 2 and Table I. We see that $_{2;1}$ and

_{2; 1} from LF agree nicely with ED, while _{1,0} does not. A likely cause of this discrepancy is the existence of a highly degenerate $(d_{SW}^0 = 9)$ spin wave energy level very close ($_{SW}^0 = 0.14258t$) to the ground state ($d_0 = 2$) at half-lling. Results of the ts for electron (n = 1) and hole (n = 1) doping are presented in Figs. 2a and 2b respectively. The NLFs were obtained using form (14) by xing the spin wave and degeneracy parameters to the values found by ED:

In the case of hole doping the spin wave term proportional to f $_{1;0}$ in the numerator of Eq. (14) has been neglected.

Examining Fig.2 we nd that inclusion of spin waves does not make a substantial di erence: LF and NLF curves are nearly overlapping [with a slight di erence around t = 2 for $\ln (Z_C (1)=Z_C (0))$] and are very close to the exact values. This insensitivity to the tting param eters m akes accurate extraction of energy gaps from partition function ratios di cult.

A nalogous simulations and LF/NLF ttings were performed for cube (C $_8$) and truncated tetrahedron (C $_{12}$) m olecules. The energy gaps measured using this procedure are summarized in Table I. The tting procedure for C $_{60}$ is described below.

B. C₆₀

Fig. 3 shows a t of the real and im aginary parts of Eq. (12) for a C $_{60}$ m olecule. The imaginary parts of the determ inant ratios are positive for > 0, which is different from the tetrahedron and truncated tetrahedron cases. The cause of this di erence is the relative size of electron and hole gaps in the system . The larger the gaps, the sm aller the corresponding canonical partition function ratios Z_{C} (n)= Z_{C} (0). For the tetrahedron and the truncated tetrahedron the electron gaps are larger than the hole gaps, so $c_1 < c_1$. In contrast, for the C_{60} m olecule the electron gap is smaller than the hole gap, so $c_1 > c_1$. Therefore, the relative size of the canonical partition function ratios results in a positive in aginary part of the determ inant ratios for > 0 in Fig. 3 due to Eq. (12). Similar ts were done for other tem peratures, and the resulting canonical partition function parameters c_n were obtained to calculate the canonical partition function ratios. Unfortunately, Eq. (14) contains too many thing parameters to provide unique ts to the data. Therefore, we had to rely on the PQMC results (at U = 4t) for the gap values

$$\begin{array}{ll} {}_{1;0} = 0.561t; & {}_{SW}^{0} = 1.06t; \\ {}_{1}^{1} = 1.39t; & {}_{SW}^{1} = 1.54t; \end{array} \tag{16}$$

and on the analysis of the molecular orbital energy level diagram (Fig. 3 of Ref. 1) for the degeneracies and their ratios

$$d_0 = 1; \quad d_{1;0} = 6; \quad d_{1;0} = 10; f_{1;0} = 120; \quad f_{1;0} = 10; \quad f_{0;0} = 30:$$
(17)

We were able to demonstrate the consistency of the results obtained by the two methods (ICPQMC and

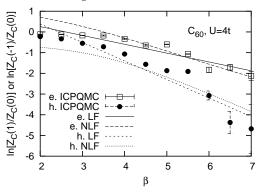


FIG. 4: Fits of ICPQMC data for a C_{60} molecule at low temperatures for electron and hole doping. e. (h.) denotes electron (hole) doping.

PQMC) by employing a following procedure. We rst let all three gap values be free thing parameters. Fitting results are then in agreement with the PQMC results, albeit with rather large uncertainties. Then we llin the two PQMC gap values $\frac{1}{5W}$ and $\frac{0}{5W}$ Eq. (16)], and let

 $_{1;0}$ be the only free parameter. This procedure, in general, yields the gap values consistent with the ones previously obtained using PQMC method [1]. Detailed results are presented in Table I with representative ts shown in Fig. 4.

IV. CONCLUSION

We have generalized the particle-hole symmetric ICPQMC simulation of D agotto et al. [6] to systems without this symmetry, such as the tetrahedron, truncated tetrahedron, and C_{60} molecule. Our simulations show that an accurate canonical partition function ratio can be obtained through this technique. Unfortunately, the tting of these ratios to obtain accurate energy gaps for C_{60} is impractical. N evertheless, consistency between ED, PQMC and ICPQMC has been found.

A cknow ledgm ents

FL thanks G raem e Luke for helpful advice on gure preparation. W e gratefully acknow ledge the support of this project by Natural Sciences and Engineering Research C ouncil (C anada), The C anadian Institute for A dvanced Research (C IAR), CFI and SHARCNET. All the calculations were carried out at SHARCNET supercom – puting facilities at M cM aster U niversity.

- F. Lin, J. Sm akov, E.S. S rensen, C. Kallin and A.J. Berlinsky, cond-mat/0411422 (2004).
- [2] R.Blankenbecler, D.J. Scalapino and R.L. Sugar, Phys. Rev.D 24, 2278 (1981).
- [3] D J. Scalapino and R L. Sugar, Phys. Rev. B 24, 4295 (1981).
- [4] JE.Hinsch, Phys.Rev.B 28, R4059 (1983); 29, 4159 (E) (1984); 31, 4403 (1985); Phys.Rev.Lett.51, 1900 (1983).
- [5] S.R.W hite et al, Phy. Rev. B 40, 506 (1989).
- [6] E.D agotto, A.M oreo, R.L.Sugar and D.Toussaint, Phys. Rev.B 41, R811 (1990).